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## 1 Introduction

Ordering matter by self-organization and self-assembly underlies numerous natural processes and opens vast opportunities in various technologies ranging from energy and environment to electronics and healthcare.<sup>1,2</sup> Among other self-organization phenomena, spinodal decomposition (SD) holds special significance because of its inherent ability to assemble nanoscale phase-separated materials from initially homogeneous crystalline solids, soft matter, and liquids. In contrast to the traditional growth of new phases by nucleation, spinodal ordering emerges in a metastable solution that is sufficiently far from equilibrium, as a regular compositional wave appearing in response to thermodynamic stimuli.<sup>3</sup> The

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# Spinodal decomposition introduces strain-enhanced thermochromism in polycrystalline  $V_{1-x}Ti_xO_2$  thin films†

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Processes of self-organization play a key role in the development of innovative functional nanocomposites, allowing, in particular, the transformation of metastable solid solutions into multilayers by activating spinodal decomposition instead of layer-by-layer film growth. We report the formation of strained layered (V,Ti) O<sub>2</sub> nanocomposites in thin polycrystalline films using a spinodal decomposition. Already during the growth of V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films, spinodal decomposition was detected while producing atomic-scale disordered Vand Ti-rich phases. Post-growth annealing enhances compositional modulation, arranges the local atomic structures of the phases, and yields periodically layered nanostructures that resemble superlattices. The coherent interfacing of the V- and Ti-rich layers results in the compression of the V-rich phase along the c-axis of the rutile structure and enables strain-enhanced thermochromism. The latter is characterized by a simultaneous decrease in the temperature and width of the metal–insulator transition in the V-rich phase. Our results provide proof-of-concept for an alternative strategy to develop VO<sub>2</sub>-based thermochromic coatings by introducing strain-enhanced thermochromism into polycrystalline thin films. PAPER<br>
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most prominent feature of SD is its capacity to assemble anisotropic condensed matter into ordered multilayers or even superlattices (SLs) without layer-by-layer epitaxy. $4-6$ 

A notable example of SD ordering is provided by the strongly anisotropic VO<sub>2</sub>-TiO<sub>2</sub> system.<sup>7</sup> The compositional wave in  $V_{1-x}Ti_xO_2$  propagates along the c-axis of the rutile structure  $(c_R)$ , producing a layered nanocomposite with alternating V- and Ti-rich phases. Strain minimization is achieved by interfacing layers along the  $a(b)$ -axis, where the lattice mismatch is smaller. By applying post-growth annealing,  $(V, Ti)O<sub>2</sub>$ nanocomposites have been fabricated in bulk polycrystalline materials, $7,8$  single crystals, $9$  epitaxial films of various orientations grown on TiO<sub>2</sub><sup>10-13</sup> and  $Al_2O_3$  substrates,<sup>14-16</sup> and, lately, polycrystalline films.<sup>17</sup> Furthermore, coherently strained SLs have been demonstrated by the enhancement of uphill diffusion during epitaxial growth on  $TiO<sub>2</sub>(001).<sup>18</sup>$ 

Ordered  $(V, Ti)O<sub>2</sub>$  multilayers are particularly intriguing because of the strongly dissimilar electronic properties of the constituent oxides. TiO<sub>2</sub> is a wide-bandgap insulator, whereas  $VO<sub>2</sub>$  is a strongly correlated material with coupled metal-insulator (MI) and structural (tetragonal–monoclinic) phase transitions.<sup>19</sup> Sharp, reversible, and tunable ultrafast changes in electrical resistivity and optical constants make  $VO<sub>2</sub>$  highly promising for a wide variety of switching and sensing devices.<sup>20</sup> In particular, because of its close to room temperature  $T_{\text{MI}}$  = 341 K and strong modulation of near-infrared (NIR) optical transmittance,  $VO<sub>2</sub>$  has been considered for a long

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time as the most favorable candidate for thermochromic coatings in energy-efficient "smart" windows.<sup>21</sup>

However, the research and development of thermochromic  $VO<sub>2</sub>$ -based coatings are still in "the infancy", because the following characteristics should be achieved simultaneously: (1)  $T_{\text{MI}} \sim 20 \div 25$  °C; (2) solar transmittance modulation,  $\Delta T_{\text{sol}}$  > 10%; and (3) integral luminous transmission,  $Tr_{\text{lum}}$  > 60%.<sup>22</sup> In addition, the MI transition should be sharp, with as narrow a thermal hysteresis loop as possible. $^{23}$  For several decades, research has primarily focused on two strategies: (1) reduction of  $T_{\text{MI}}$  by doping<sup>24</sup> and (2) increasing  $T_{\text{Ium}}$  by implementing a nanothermochromic concept, based on the embedment of  $VO<sub>2</sub>$  nanoparticles into a transparent matrix,<sup>25</sup> or by combining both strategies.26 Consequently, the issue of ineffective switching behaviour remains unaddressed, and reliable  $VO<sub>2</sub>$ based thermochromic coatings are still unavailable. Moreover,  $VO<sub>2</sub>$  doping is accompanied by degradation of the NIR transmittance switching owing to the broadening of the MI transition. The vital demand for an alternative strategy for tailoring NIR switching has recently resulted, for instance, in the hybridization of  $VO<sub>2</sub>$  films with plasmonic TiN nanoparticles.<sup>27</sup>

Herein, we propose an alternative strategy based on straindriven reduction of the  $T_{\text{MI}}$  and the width of the MI transition. Coherent epitaxial strains have been widely exploited to tune the functional characteristics of transition metal oxides, including  $\text{VO}_2$ .<sup>28,29</sup> In contrast to doping, compressive strain along the  $c_R$ -axis results in a reduction in  $T_{\text{MI}}$  without an undesirable broadening of the MI transition. $30,31$  Unfortunately, the use of strain engineering for tuning  $T_{\text{MI}}$  is intimately linked to epitaxial growth, which is inapplicable to thermochromic coatings, as they must be deposited on an amorphous glass substrate. In the  $VO_2$ -TiO<sub>2</sub> system, the necessity for epitaxial growth can, in principle, be overcome using a strained layered nanocomposite formed by the SD process, which must be executed in a thin polycrystalline film. To date, the optical and thermochromic properties of  $(V, Ti)O<sub>2</sub>$ -based nanocomposites have been studied exclusively for epitaxial films.<sup>12,14</sup> However, strong elastic coupling (clamping) of the epitaxial film and substrate makes strain-enhanced thermochromism unattainable.

In this study, we performed SD in polycrystalline thin films of  $V_{1-x}Ti_xO_2$  grown on fused quartz substrates, examining thus spinodal ordering inside small grains with a lateral size  $D < 100$  nm.

The composition of the solid solution was adjusted to  $x =$ 0.35, that is to the center of the miscibility gap for the  $VO_2 TiO<sub>2</sub>$  system, which is known to be optimal for SD.<sup>7</sup> Next, postgrowth annealing was performed to accomplish decomposition. The structural and thermochromic properties of the asgrown and annealed films were studied to disclose the SD features in the fine grains and to estimate the potential of our strategy for the fabrication of thermochromic coatings.

## 2 Experimental details

Thin film samples were grown using a solution-based chemical technique of metalorganic aerosol deposition<sup>32</sup> (MAD), which

is founded on the pyrolysis of precursors at the surface of a heated substrate. The deposition system was equipped with a pneumatic nebulizer (MEINHARD®) for spray flux generation and various controllers and sensors to regulate deposition parameters such as substrate temperature,  $T_{\text{sub}}$ , Ar and  $O_2$  gas flows, spray flux intensity, pressure *etc*. To stabilize the  $V^{4+}$ valence state, the growth of VO<sub>2</sub> and V<sub>1-x</sub>Ti<sub>x</sub>O<sub>2</sub> films was performed under oxygen-deficient conditions by using a mixture of Ar and  $O<sub>2</sub>$  gases. Regardless of the gas mixture composition, the total pressure inside the chamber was maintained at 750 mbar to ensure a constant distribution of the spray over the substrate.  $OV(acac)_2$  and  $Ti(O-i-Pr)_2(TMHD)_2$  precursors were dissolved in dimethylformamide with a concentration of 0.05 M  $l^{-1}$  for fabrication of pure-phase VO<sub>2</sub> and TiO<sub>2</sub> films, respectively; a mixture of the precursors was employed for deposition of  $V_{1-x}Ti_xO_2$  films. The 10 × 10 × 0.5 mm substrates of 2-side polished fused quartz were used for the deposition of polycrystalline films. Additionally,  $Al_2O_3(0001)$  substrates were utilized for the optimization of  $VO<sub>2</sub>$  synthesis. To prevent vanadium over-oxidation, spinodal decomposition of the  $V_{0.65}Ti_{0.35}O_2$  films was performed by annealing in a pure Ar atmosphere at a pressure of 1000 mbar. Nanoscale Worwingtone (and identical contribution on 20 June 2023. Downloaded on the superposition of the superposit

The surface morphology of the films was characterized using either a Zeiss Leo Supra 35 field-emission gun scanning electron microscope (SEM) or a Park System XE7 atomic force microscope (AFM). The composition of the solid-solution films was estimated by energy dispersive X-ray (EDX) elemental analysis using the same SEM. Using a Bruker D8 Advance diffractometer (Cu<sub>K $\alpha$ </sub> radiation), the thickness of the films was determined from X-ray reflection (XRR) oscillations by plotting the reflection intensity versus the momentum transferred perpendicular to the sample, which is defined by  $\left(\frac{2\pi}{\lambda}\right)$  sin  $\theta$ ; the roughness of thick polycrystalline films was too high to determine their thickness by XRR.

The microstructure of the films and the local V/Ti chemical composition were analyzed using a FEI TITAN 80-300 environmental transmission electron microscope (TEM) operating at 300 kV and equipped with a Gatan imaging filter (Quantum 965 ER). Bright-field (BF) and high-angle annular dark field (HAADF) images were acquired in the scanning TEM (STEM) mode after the collection of electron energy-loss spectra (EELS). The analysis of crystalline phases was performed by X-ray diffraction (XRD) using a Malvern Panalytical Empyrean 2 diffractometer (λ = 1.54098 Å) in grazing incidence mode (θ = 0.5°). A dedicated X-ray server $33$  was used to estimate the residual strains in polycrystalline  $V_{1-x}Ti_xO_2$  films by numerically fitting the XRD patterns. To simulate peak broadening, the XRD patterns were represented as a sum of reflections from numerous individual grains by varying their parameters (grain size, number of compositional layers, and their thickness) around the average values, which were determined using TEM. Micro-Raman analysis was carried out at room temperature in a backscattering geometry with a continuous wave Nd:YAG laser  $(\lambda =$ 532 nm) using a confocal Raman microscope (LabRAM HR Evolution, Horiba JobinYvon); to avoid significant heating of the sample, the laser power was reduced down to 0.2 mW.

The electrical resistivity of the samples was measured using the four-electrode method (silver paint contacts) at temperatures ranging from 300 to 400 K in a physical property measurement system (PPMS, Quantum Design) with a heating/ cooling rate of 2 K min<sup>-1</sup>. Temperature-dependent optical transmission at wavelengths of 400–2500 nm was measured using a custom-assembled setup based on: (1) two spectrometers (Maya2000Pro for 165–1100 nm and NIRQuest512- 2.5 for 900–2500 nm, both by OceanOptics); (2) the corresponding Vis and NIR light sources (DH-2000 and HL-2000- FHSA, both by OceanInsight); and (3) the temperature-controlled stage (THMS350V, Linkam Scientific) for mounting samples. The integrated solar transmittance (250–2500 nm) was calculated as follows:

$$
Tr_{\rm sol} = \int_{250}^{2500} \psi_{\rm sol}(\lambda) Tr(\lambda) d\lambda / \int_{250}^{2500} \psi_{\rm sol}(\lambda) d\lambda,
$$

where  $T(\lambda)$  represents the transmittance at wavelength  $\lambda$  and  $\psi_{sol}$  is the solar irradiance spectrum for an air mass of 1.5. The solar modulation ability was calculated as follows:

$$
\Delta \text{Tr}_{sol} = \Delta \text{Tr}_{sol,IT} - \Delta \text{Tr}_{sol,hT},
$$

where lT and hT represent 25 °C and 100 °C, respectively. The integral luminous transmittance (350–750 nm) was calculated using the equations:

$$
Tr_{\text{lum}} = \int_{350}^{750} \phi_{\text{lum}}(\lambda) Tr(\lambda) d\lambda / \int_{350}^{750} \phi_{\text{lum}}(\lambda) d\lambda,
$$

where  $\varphi_{\text{lum}}$  is the standard luminous efficiency of photopic vision.

## 3 Results and discussion

### 3.1 Thin film growth and annealing

Because of the abundant vanadium valences ranging from  $2^+$ to  $5^+$ , over 20 oxide phases can be produced.<sup>34</sup> Therefore, the growth conditions for the pure-phase  $VO<sub>2</sub>$  synthesis were firstly optimized and these conditions were further applied to prepare the  $V_{1-x}Ti_xO_2$  solid solution. The growth parameters of VO<sub>2</sub> are interrelated, and a higher  $T_{sub}$  or deposition rate requires an increase in oxygen content.<sup>35</sup> Subsequently, we optimized  $VO_2$  synthesis by regulating  $O_2$  flow only, as the most sensitive parameter, keeping fixed the rest of them: (1) Ar + O<sub>2</sub> gas flow at 1000 cm<sup>3</sup> min<sup>-1</sup>, (2)  $T_{sub}$  = 470 °C, and (3) deposition rate at 1 nm  $s^{-1}$ . XRD analysis of crystalline phases, used for a prior optimization, shows that for the  $O<sub>2</sub>$  flow below 10 cm<sup>3</sup> min<sup>-1</sup> all XRD peaks belong to the monoclinic VO<sub>2</sub> phase, forming typical patterns for polycrystalline (Fig. 1a) and (010)-oriented (Fig. 1b) films grown on fused quartz and  $Al_2O_3(0001)$ , respectively. Precise tuning of the  $O_2$  flow was then carried out by measuring the temperature-dependent resistance,  $R(T)$ , because the value of  $T_{\text{MI}}$  and the form of the hysteresis loop proved to be more sensitive to the  $VO<sub>2</sub>$  off-stoichiometry. Thereby, we found that only a narrow  $O_2$  flow interval of around 4 cm<sup>3</sup> min<sup>-1</sup> ensures a pure-phase VO<sub>2</sub> synthesis.

SEM images of the  $VO<sub>2</sub>$  films grown under the optimized conditions on fused quartz and  $Al_2O_3(0001)$  substrates are presented in Fig. 1c and d, respectively. Both surfaces are composed of densely packed grains, but their average sizes are quite different: they reach  $D \sim 120$  nm in the polycrystalline film and  $D \sim 40$  nm in the single-oriented film of the same thickness. The smoother surface of the oriented film on sapphire allowed us to determine the film thickness of  $d \sim 83$  nm by XRR (the insert on Fig. 1b). The  $R(T)$  curves shown in Fig. 1e reveal the same  $T_{\text{MI}}$  = 68 °C both for the polycrystalline and the single-oriented films; here  $T_{\text{MI}}$  was determined as a middle temperature between  $TCR(T)$  minima (see the inset in Fig. 1e). However, the width, sharpness, and amplitude of the hysteresis loops are predictably different because of the large contribution of irregular grain boundaries in the polycrystalline material. The obtained  $T_{\text{MI}}$  value exactly fits the tabulated value for pristine  $\text{VO}_2$ .<sup>19</sup> The observed metallic behavior above  $T<sub>MI</sub>$  in the single-oriented film (see the zoomed area of the  $R(T)$  curve in Fig. 1e) confirms the achievement of pure-phase  $VO<sub>2</sub>$  synthesis. Paper<br>
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Titanium is less prone to phase variation, displaying a valence state of 4+ for all oxygen pressures that are higher than the minimum value required for stoichiometric  $TiO<sub>2</sub>$  formation. Therefore, before  $V_{1-x}Ti_xO_2$  deposition, we verified the formation of  $TiO<sub>2</sub>$  under the optimal conditions for synthesizing pure-phase VO<sub>2</sub>, *i.e.* under ∼0.4% oxygen in an Ar + O<sub>2</sub> atmosphere. The obtained films were insulating with a sheet resistance above  $10^8$  Ω. Fig. S1† presents the results of characterization for a TiO<sub>2</sub> film grown on a fused quartz substrate. The AFM image in Fig. S1a† demonstrates the typical surface of a polycrystalline film comprising grains with an average size of  $D \sim 60$  nm. This surface morphology was sufficiently smooth to develop XRR oscillations (see Fig. S1b†) and to determine the film thickness  $d = 34$  nm. All XRD peaks in Fig. S1c† belong to the rutile TiO<sub>2</sub> structure, confirming thus the formation of TiO<sub>2</sub> under  $O_2$  content of 0.4%.

To fabricate  $V_{1-x}Ti_xO_2$ , a specified quantity of the V precursor was replaced with the Ti precursor, maintaining the integral molarity of the mixed precursor solutions and all other growth conditions constant. A fast cooling rate of ∼100 °C  $min^{-1}$  was applied after film growth to freeze out the metastable state of the obtained solid solution. Fig. 1f shows the XRD patterns of the two  $V_{1-x}Ti_xO_2$  films with different Ti contents. One can see that, regardless of the Ti/V precursor ratio, XRD reveals peaks belonging to the solid solution only. The texture shifts towards the (110)-orientation with an increase in the Ti-content, but all peaks correspond to the rutile structure and are located between those seen for pristine  $VO<sub>2</sub>$  and TiO<sub>2</sub>. This result is in line with rutile structure formation at  $x > 0.2$ in the bulk polycrystals.<sup>7</sup> According to Vegard's law, the compositions of the  $V_{1-x}Ti_xO_2$  films in Fig. 1f correspond to  $x_1 =$ 0.26 and  $x_2$  = 0.43. By tuning the Ti/V ratio we obtained the



Fig. 1 Characterization of VO<sub>2</sub> and V<sub>1−x</sub> Ti<sub>x</sub>O<sub>2</sub> thin films. XRD patterns of VO<sub>2</sub> films grown on (a) fused quartz and (b) Al<sub>2</sub>O<sub>3</sub>(0001) substrates (the sapphire peaks are denoted by s); the inset in (b) shows the XRR oscillations of the 83 nm-thick film. SEM images of VO<sub>2</sub> films grown on (c) fused quartz and (d)  $Al_2O_3(0001)$  substrates. (e) Temperature-dependent resistance of VO<sub>2</sub> films grown on  $Al_2O_3(0001)$  (olive) and fused quartz (orange) substrates; the insert shows the thermal coefficients of resistance, TCR(T) = 100% x (1/R)(dR/dT). The magnified area in (e) demonstrates the metallic conductivity of the VO<sub>2</sub> film grown on Al<sub>2</sub>O<sub>3</sub>(0001). (f) XRD patterns of two V<sub>1−x</sub>Ti<sub>x</sub>O<sub>2</sub> films with x<sub>1</sub> = 0.26 (orange) and x<sub>2</sub> = 0.43 (blue); the inset demonstrates shifting of the (211)-peak with x. (g) SEM image of 180 nm-thick V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films grown on fused quartz substrate. (h) Temperaturedependent resistance of as-grown (blue) and annealed (red) at 530 °C for 1 hour V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> film; the inset shows TCR(T) of the annealed film.

solid solution with nominal value of  $x = 0.35$  required for further SD processing. In Fig. 1g the SEM image shows the surface morphology of a 180 nm-thick  $V_{0.65}Ti_{0.35}O_2$  film with an average grain size of  $D \sim 120$  nm. The EDX spectrum in Fig. S2† corresponds to the metal stoichiometry of  $V_{0.66}Ti_{0.34}$ , confirming thus the compositional analysis performed by XRD.

The SD was then activated by a step-by-step increase in either the temperature or duration of post-growth annealing. We observed that the surface morphology and average composition of the solid solution films remained unchanged (not shown) during all annealing cycles. However, the  $R(T)$ dependence changed after exposure to 530 °C for 1 h, transforming from a gradual dependence into a hysteresis loop, as shown in Fig. 1h. The observed resistance switching suggests the onset of the MI transition in the  $V_{0.65}Ti_{0.35}O_2$  film owing to the appearance of the V-rich phase. It is worth noting that our attempts to further increase either the temperature or duration of annealing resulted in deterioration of the  $R(T)$  hysteresis loop. In comparison with the  $R(T)$  dependence in Fig. 1e for the optimized  $VO<sub>2</sub>$ , the resistance switching of annealed  $V_{0.65}Ti_{0.35}O_2$  in Fig. 1h is shifted towards a lower temperature, implying an essential difference between the emerged V-rich phase and the pure-phase  $VO<sub>2</sub>$ .

### 3.2 TEM analysis

The microstructures of the as-grown and annealed  $V_{0.65}Ti_{0.35}O_2$  films were analyzed by TEM and compared with that of pure  $VO<sub>2</sub>$  polycrystalline film. The top row in Fig. 2 presents the plan-view BF STEM images of  $VO<sub>2</sub>$  (a), as-grown (b), and annealed (c)  $V_{0.65}Ti_{0.35}O_2$ . In contrast to VO<sub>2</sub>, a periodic alternation of bright and dark stripes appeared in both  $V_{0.65}Ti_{0.35}O_2$  samples. The cross-sectional BF STEM image shown in Fig. 2d also reveals the striped microstructure of the annealed  $V_{0.65}Ti_{0.35}O_2$  film. The V- and Ti-rich layers appear in the BF images as dark and bright strips, respectively. In bulk polycrystalline materials, the alternation of bright and dark



Fig. 2 TEM analysis of VO<sub>2</sub> and V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films grown on fused quartz substrates. Plan-view BF STEM images of (a) VO<sub>2</sub>, (b) as-grown, and (c) annealed V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films. (d) Cross-sectional BF STEM image of annealed V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films. HAADF-STEM images and respective EELS maps of as-grown (e) and annealed (f)  $V_{0.65}Ti_{0.35}O_2$  films; V is marked as orange and Ti as blue.

bands indicates the separation of the V- and Ti-rich phases that emerge as a result of  $SD<sup>7</sup>$  Note that the striped microstructure can be observed by TEM only in the grains for which the direction of compositional modulation coincides with the image plane. In otherwise oriented grains, the elemental contrast is screened by the overlapping layers. By choosing correctly oriented grains, the estimated thickness of the individual layers is equal to ∼8 nm for the Ti-rich layers and ∼12 nm for the V-rich ones. The observed layered nanostructures contain stacking faults and "curved" layers, which result from the irregular shape of the crystallites and a limited number of layers embedded in the nano-sized grains.

Thus, TEM analysis confirmed the realization of SD in the small crystallites of thin polycrystalline films. Moreover, it was revealed that a layered nanocomposite also forms in the asgrown  $V_{0.65}Ti_{0.35}O_2$  film, pointing out that SD occurs even during film growth. The presence of a layered structure signifies the spinodal nature of phase separation during growth; the alternative process of phase separation through nucleation and growth can only yield nanodot or nanopillar-embedded composites due to the isotropy of adatom surface mobility on the amorphous substrates. The development of SD during film growth has been predicted theoretically $37$  and observed experi-

mentally in epitaxial  $(V, Ti)O<sub>2</sub>$  films.<sup>18</sup> However, the observed here nanoscale phase separation in the as-grown  $V_{0.65}Ti_{0.35}O_2$ contradicts the gradual  $R(T)$  behavior in the as-grown sample (see Fig. 1h), apparently contrasting with a robust hysteresis loop appeared after the annealing. The lack of resistance switching in the as-grown films can be rationalized by comparing the elemental compositions of the V- and Ti-rich layers before and after annealing. HAADF STEM images with corresponding the EELS elemental maps are shown in Fig. 2e and f for the as-grown and annealed  $V_{0.65}Ti_{0.35}O_2$  films, respectively. The bright and dark strips in the HAADF STEM image correspond to the V (red) and Ti (blue) areas, respectively, in the EELS elemental maps. The Ti content in the as-grown film corresponds to  $x = 0.41$  in the Ti-rich layers and  $x = 0.24$  in the V-rich ones. After annealing, the degree of compositional modulation becomes notably higher:  $x = 0.45$  (Ti-rich) and  $x =$ 0.19 (V-rich). It was established<sup>7</sup> that the value of  $x < 0.2$  is necessary for efficient V–V dimerization, which is an essential prerequisite of the MI transition in  $VO<sub>2</sub>$ . Thus, the observed compositional modulation in the as-grown film, i.e.  $V_{0.76}Ti_{0.24}O_2$ , is insufficient for V–V dimerization and the onset of MI transition. Post-growth annealing resulted in the formation of  $V_{0.81}Ti_{0.19}O_2$  layers with a sufficiently high concen-

tration of V for the manifestation of a pronounced MI transition in  $R(T)$  dependence.

### 3.3 XRD analysis

XRD patterns in Fig. S3† reveal a broadening of the (101), (111), and (211) peaks after post-growth annealing, whereas the (110), (200), and (210) peaks remain unchanged. Because broadening was detected only for  $(hkl)$ -peaks with  $l = 1$ , the compositional modulation is directed along the  $c_R$ -axis<sup>7</sup> and is independent of the grain orientations. In Fig. 3 a detailed XRD pattern near the broadened (101)-peak of  $V_{0.65}Ti_{0.35}O_2$  is shown together with the corresponding peaks of the  $VO<sub>2</sub>$  and  $TiO<sub>2</sub>$  films. Two important changes induced by annealing can be observed: (1) the (101)-peak shifts toward a larger  $2\theta$ -angle; and (2) two small peaks appear symmetrically on both sides of the main (101)-peak. The observed shift indicates either a change in the film composition or a strained state of the layered nanocomposite. According to the EDX data, the average film composition did not change after the annealing. Therefore, we can attribute this shift to a decrease in the c-lattice parameter from 0.2250 to 0.2247 nm, which indicates residual compressive strain. The reason for compression is the coherent interfacing of the V- and Ti-rich layers along the  $a(b)$ axis in the presence of a lattice mismatch (0.86% between pristine  $VO<sub>2</sub>$  and TiO<sub>2</sub>). Coherent interfacing results in compressive and tensile strains along the  $c_R$ -axis in the V- and Ti-rich layers, respectively. The overall shift of the main peak to a larger 2 $\theta$ -angle means that shrinking  $c_R$  in V-rich layers overcomes its expansion in Ti-rich layers. Note that the as-grown  $V_{0.65}Ti_{0.35}O_2$  film appears to be unstrained, and this state coexists with a level of compositional modulation that is insufficient to exhibit a hysteresis loop in the  $R(T)$  dependence.

The appearance of two minor peaks after annealing (Fig. 3) was more intriguing. In principle, by stopping the SD process



Fig. 3 Normalized XRD patterns next to the  $(101)$  peaks of TiO<sub>2</sub> (purple),  $VO<sub>2</sub>$  (blue), as-grown (magenta), and annealed (olive) V0.65Ti0.35O2 films grown on fused quartz substrates. Simulated XRD (orange) of polycrystalline film with grains comprised  $V_{0.81}Ti_{0.19}O_2/$  $V_{0.55}Ti_{0.45}O_2$  superlattices. The positions of the (101) peaks are indicated by the vertical dashed lines in the respective colors.

at the initial stage, it is possible to acquire an XRD pattern comprising both the initial peak of the solid solution and two minor peaks, which correspond to the incipient V- and Ti-rich phases. However, TEM analysis revealed a significant degree of phase separation even before and, especially, after the annealing of  $V_{0.65}Ti_{0.35}O_2$ . Moreover, the angular distance between the main and minor peaks is too large; the minor peak at a larger 2θ-angle corresponds to a compressed pure phase of  $VO<sub>2</sub>$ , but the EELS analysis established a V-rich phase composition of  $V_{0.81}Ti_{0.19}O_2$ . Therefore, another origin for the minor peaks must be supposed. Because the minor peaks appear at equal distances from the main one, we suppose that these peaks represent satellites SL−<sup>1</sup> and SL+1 of the main superlattice peak  $SL<sub>0</sub>$ . That is, the appearance of minor peaks points to the right periodicity of  $V_{0.81}Ti_{0.19}O_2$  and  $V_{0.55}Ti_{0.45}O_2$  layers. By applying Schuller's formula<sup>38</sup> for superlattices  $\Lambda = \lambda/(\sin \theta_n - \pi)$  $\sin \theta_{n-1}$ ), a superlattice period  $\Lambda = 20.6$  nm was determined. This value agrees very well with the sum of the V- and Ti-rich layer thicknesses, *i.e.*  $12 + 8 = 20$  nm, as observed by TEM (Fig. 2). By numerically fitting the XRD patterns, we estimated the individual values of the residual strains in the V- and Tirich layers. The best agreement between the simulated and experimental curves in Fig. 3 was achieved at the same value of the lattice strain parameter,  $\Delta c/c = 0.01 \div 0.014$ , in both layers. Considering that compressed V-rich layers are 1.5 times thicker than tensile Ti-rich layers, the average lattice parameter of the whole SL decreases and the position of the central  $SL_0$ peak shifts toward a higher 2θ-angle. Nanoscale Workers Articles. We<br>where  $\theta$  and the components of a pronounced M1 turn- art the initial stage, it is possible to sequen and Nature<br>31.3 MD analysis (and the initial stage, it is possible to the significant<br>s

### 3.4 Raman analysis

Despite the considerable compositional modulation, SL peaks were absent in the as-grown  $V_{0.65}Ti_{0.35}O_2$  films. Therefore, along with the quantitative enhancement of the compositional modulation revealed by TEM, post-growth annealing results in a distinct structural transformation. Raman spectroscopy allows us to elucidate this transformation. Fig. 4 shows the Raman spectra of a  $V_{0.65}Ti_{0.35}O_2$  film before and after annealing, as well as the spectrum of a pure-phase  $VO<sub>2</sub>$  film and reference data for rutile  $\text{TiO}_2$ .<sup>39</sup> Almost all phonon modes of monoclinic VO<sub>2</sub><sup>40</sup> were identified in the spectrum of the VO<sub>2</sub> film. The spectrum of the annealed  $V_{0.65}Ti_{0.35}O_2$  film reproduces most of the  $VO<sub>2</sub>$  modes, but with a shift towards smaller wavenumbers, e.g., the A<sub>q</sub> mode shifts from 613 cm<sup>-1</sup> to 602 cm−<sup>1</sup> . This shift is caused by the formation of a solid solution because the replacement of V with Ti increases the bond length at almost identical binding energies of the Ti–O and V– O bonds. $41$ 

The Raman spectrum of the as-grown  $V_{0.65}Ti_{0.35}O_2$  film, which lacks almost all phonon modes, differs drastically from those measured for  $VO_2$  and annealed  $V_{0.65}Ti_{0.35}O_2$  films. It consists of only a  $602 \text{ cm}^{-1}$  mode, which is broader and weaker than that of the annealed  $V_{0.65}Ti_{0.35}O_2$  film. Because XRD reveals robust crystallinity in the as-grown film, we cannot attribute such strong damping of almost all phonon modes to an amorphous state of  $V_{0.65}Ti_{0.35}O_2$ . It is likely that the observed contradiction between XRD and Raman spec-



Fig. 4 Room-temperature micro-Raman spectra acquired on the purephase  $VO<sub>2</sub>$  film (blue), as-grown (magenta), and annealed (green) at 530 °C for 1 hour  $V_{0.65}Ti_{0.35}O_2$  films grown on fused quartz substrates. Diamonds indicate the tabulated  $VO<sub>2</sub>$  modes. The vertical dashed lines show the correspondence between the lines in the VO<sub>2</sub> and  $V_{0.65}Ti_{0.35}O_2$  spectra. The orange strips denote the positions and relative intensities of rutile TiO<sub>2</sub> lines.

troscopy is caused by the different probing scales of these methods. Raman spectroscopy is sensitive to the local atomicscale coordination, which is determined mainly by the nearest neighbors and to a lesser extent by the next to nearest-neighbor atoms, i.e. the probing scale is ∼1–2 unit cells.<sup>42</sup> The coherence scattering length of XRD in polycrystalline materials is limited by the size of the crystallites. By applying Scherrer's formula  $L = 0.9\lambda/\beta \cos \theta$ , where L is the crystallite size,  $\lambda$  is the X-ray wavelength,  $\beta$  is the full width at half maximum of the diffraction peak, the estimated average grain size in the  $V_{0.65}Ti_{0.35}O_2$  film is  $L \approx 50$  unit cells. This size exceeds the probing scale of Raman spectroscopy by many times. Therefore, the observed contradiction can be explained by the difference between the local atomic structure and long-range or mesoscopic structure (crystallite). The local disorder in the metastable  $V_{0.65}Ti_{0.35}O_2$  solid solution stems from the inhomogeneous distribution of Ti and V atoms during growth. The alloying-induced disorder was frozen by the fast cooling after film growth, producing thus numerous local microphases with various arrangements of V–Ti atomic chains. Raman spectroscopy is able to detect vibrational modes from similar micro-phases developing in a random solid solution.<sup>43</sup> In our case, the overlapping of slightly displaced vibrational modes from different microphases results in the observed broadening of the most intensive  $A_{\varrho}$ -peak and damping of the rest of peaks with a smaller intensity. Hence, the results of Raman spectroscopy allowed us to conclude that upon annealing, the random solid solutions in the V- and Ti-rich layers underwent a structural transformation into short-range ordered states.

### 3.5 Optical transmittance

Using  $R(T)$  measurements, we detected the onset of the MI transition in the  $V_{0.65}Ti_{0.35}O_2$  film after annealing. However, percolative transport through the two-phase nanocomposite,

where only V-rich layers undergo the MI transition, causes smearing of the hysteresis loop in  $R(T)$ . Optical transmittance measurements allowed us to uncover the characteristics of the MI transition in the V-rich phase and to elucidate the thermochromic properties of the  $(V, Ti)O<sub>2</sub>$ -nanocomposite. Fig. 5 presents the temperature-dependent Vis–NIR optical transmittance of a pure  $VO<sub>2</sub>$  film in comparison with the as-grown and annealed  $V_{0.65}Ti_{0.35}O_2$  films.

The Vis–NIR transmittance spectra in Fig. 5a were measured well below (25 °C) and above (100 °C) the standard  $T_{\text{MI}}$  = 68 °C for pristine VO<sub>2</sub>. The spectra of the VO<sub>2</sub> film demonstrate a typical transition-induced change in the NIR transmittance,  $\Delta T r = 38\%$  at 1700 nm, for a film thickness  $d =$ 83 nm. The as-grown 180 nm-thick  $V_{0.65}Ti_{0.35}O_2$  film exhibited a negligible change,  $\Delta T r = 7\%$ . However, the emergence of MI transition after annealing led to an increase in  $\Delta T r$  to 29%. Fig. 5b shows the temperature-dependent integral solar transmittance,  $\Delta T r_{\text{sol}}$ , for wavelengths  $\lambda = 250-2500$  nm for the VO<sub>2</sub> and  $V_{0.65}Ti_{0.35}O_2$  films shown in Fig. 5a. The main MI transition characteristics  $(T_{\text{MI}})$ , width, and amplitude of the hysteresis loop) are shown in Fig. 5c by plotting the derivative  $dT_{sol}$  $dT$  and fitting the curves using Gaussians. Here,  $T_{\text{MI}}$  is determined as the middle temperature between the derivative minima for the heating and cooling curves. The pure  $VO<sub>2</sub>$  film demonstrated a tabulated MI transition temperature,  $T_{\text{MI}}$  = 68 °C, confirming the value evaluated from  $R(T)$  in Fig. 1e. The solar modulation ability,  $\Delta T_{\text{Sol}} = 12\%$ , and width of the thermal hysteresis loop,  $\Delta T_{\text{MI}} = T_{\text{MI}}$  (heating) –  $T_{\text{MI}}$  (cooling) = 16 °C, agree well with those reported for high-quality polycrystalline  $VO<sub>2</sub>$  films of comparable thickness.<sup>44</sup> The as-grown  $V_{0.65}Ti_{0.35}O_2$  film demonstrates a lack of hysteresis behavior similar to the  $R(T)$  measurements, exhibiting a weak gradual decrease of  $T_{sol}$  with temperature and a low solar modulation  $\Delta T r_{\rm sol}$  = 3%, which appears because of the variation in the optical constants with temperature. In contrast, the onset of the MI transition in the V-rich layers after annealing led to a pronounced hysteresis loop, which demonstrated a reduced  $T_{\text{MI}}$  of 53 °C, a decreased  $\Delta T_{\text{MI}}$  of 9 °C, and an enhanced  $\Delta T r_{\rm sol}$  of 14%. Paper **Commons Commons Article** Conservation of the common of the common and the common attention of the common and the common and the common and

> The observed change in  $\Delta T_{\text{sol}}$  can be interpreted as a result of the increased  $VO<sub>2</sub>$  content in the 180 nm-thick  $V_{0.65}Ti_{0.35}O_2$  film compared to that in the 83 nm-thick purephase VO<sub>2</sub> film. However, the simultaneous decrease in  $T_{\text{MI}}$ and  $\Delta T_{\text{MI}}$  can only be caused by compressive strains in the V-rich layers because simple alloying of  $VO<sub>2</sub>$  with  $TiO<sub>2</sub>$  leads to an extended transition at elevated  $T_{\text{MI}}^{45}$  The emergence of strain-enhanced optical characteristics after annealing was in full agreement with the formation of a strained superlattice-like microstructure, as revealed by XRD. The lack of the substrate clamping effect causes the independence of interfacial strains on the grain orientation and leads to a reduction of  $T_{\text{MI}}$  by 15 °C, which substantially exceeds the 5–6 °C reduction observed in the presence of the clamping effect in epitaxial films.<sup>15</sup>

> Despite the ~40% excess in VO<sub>2</sub> content, the V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> and VO<sub>2</sub> films possess almost the same values of  $T_{\text{Ium}}$ , 29.0 and 28.9%, respectively. According to the nanothermochromic



Fig. 5 Optical properties of 83 nm-thick VO<sub>2</sub> films (top panels) in comparison with 180 nm-thick as-grown (middle panels) and annealed (bottom panels) V<sub>0.65</sub>Ti<sub>0.35</sub>O<sub>2</sub> films all deposited on fused quartz substrates. (a) Vis–NIR transmittance spectra at 25 and 100 °C. (b) Temperature-dependent integral solar transmittance in the 250 ÷ 2500 nm range of wavelengths. (c) Derivatives of integral solar transmittance: experimental points and Gaussian fittings.

concept, VO<sub>2</sub> nanoparticles embedded in a transparent dielectric host provide a higher  $Tr_{\text{lum}}$  than VO<sub>2</sub> films of an equivalent thickness.<sup>25</sup> In our case, the layers of a more transparent  $TiO<sub>2</sub>$ rich phase produced the nanothermochromic effect, maintaining  $Tr_{\text{lum}}$  at the same value despite an increase in the equivalent VO<sub>2</sub> thickness.

### 3.6 Discussion

We established that spinodal decomposition can be performed in small grains of thin polycrystalline  $V_{1-x}Ti_xO_2$  films in the same manner as in bulk materials and epitaxial films. In addition to a basic similarity, two essential differences were observed: (1) SD develops simultaneously with film growth, producing a significant phase separation in the as-grown  $V_{0.65}Ti_{0.35}O_2$  films, and (2) post-growth annealing results in the formation of strained superlattice-like  $(V, Ti)O<sub>2</sub>$  nanostructures.

An in situ SD during film growth has already been observed in epitaxial (V,Ti)O<sub>2</sub> films when the  $c_R$ -axis coincides with the film growth direction.<sup>18</sup> In our case, the direction of compositional modulation was irrelevant to the grain orientation, and the SD was identical to that in the bulk materials. We suppose that enhanced surface adatom diffusion is responsible for SD during growth, whereas bulk diffusion occurs under post-grown annealing. The enhancement of surface diffusion stems from the main peculiarities of MAD growth: (1) being a chemical technique, MAD operates under nearequilibrium growth conditions, promoting surface diffusion;

(2) the pyrolysis of precursors such as β-diketonates of V and Ti is an exothermic reaction, resulting in an additional increase in the surface temperature, which leads to an extra enhancement of surface diffusion. However, adatom diffusion is kinetically limited by deposition rate. As a result, phase separation during growth was incomplete, yielding an insufficient concentration of V to achieve the MI transition in V-rich layers. Moreover, Raman spectroscopy revealed a disordered state in the as-grown solid solutions, with an inhomogeneous local distribution of V and Ti atoms. Such random solid solutions possess diffused interfaces; thus, they are inconsistent with the formation of strained nanocomposites via coherent interfacing between layers. Therefore, neither superlattice-like nanostructure nor MI transition were observed in the as-grown  $V_{0.65}Ti_{0.35}O_2$  films.

The activation of bulk diffusion by post-growth annealing results in predictable strengthening of the compositional modulation, yielding also strained superlattice-like nanostructures. This is the most remarkable feature revealed by XRD analysis in the thin polycrystalline  $V_{0.65}Ti_{0.35}O_2$  films. The corresponding transformation of the optical properties, i.e. a simultaneous decrease in  $T_{\text{MI}}$  and  $\Delta T_{\text{MI}}$ , confirms the strained state after annealing. In principle, the formation of SLs is the conventional termination step of the SD process.<sup>4</sup> Nevertheless, suitable conditions for SL formation are hardly accessible because of (1) the pinning of compositional waves at various structural imperfections and (2) the development of

new phases by concurrent processes of nucleation. We suppose that in our case, a fine grain size,  $D \sim 30-100$  nm, facilitates the formation of superlattices. In bulk materials, the result of SD is determined by the superposition of numerous compositional waves initiated in different parts of a large crystalline grain,  $D > 0.5$  µm for bulk polycrystals<sup>7</sup> or mm-size single crystals.<sup>9</sup> For a grain size of only several tens of nanometers, it is plausible to suppose that a single compositional wave propagates over the entire crystallite, forming a superlattice-like structure of just a few periods.

As a moderate SD level has been obtained during film growth, it raises the question of whether a higher level of compositional modulation can be achieved during growth without a considerable increase in substrate temperature. This is a key challenge for the practical application of  $(V, Ti)O<sub>2</sub>$ -based nanocomposites as thermochromic coatings because the thermal budget of smart window fabrication is limited by the glass transition temperature. We obtained an enhanced surface adatom mobility during growth at  $T_{sub} = 470$  °C. To activate bulk diffusion, we applied post-growth annealing at 530 °C, exceeding thus the deposition temperature by 60 °C only. We believe that further enhancement of surface diffusion during film growth can be achieved either (1) by overcoming the kinetic limitation using a reduced deposition rate or (2) by preventing the formation of foreign phase inclusions, which interrupt the diffusion flux. The latter stems from the fact that the SD in bulk polycrystals can be activated at temperatures as low as 400 °C (ref. 7) and the most probable structural defects in the VO<sub>2</sub>–TiO<sub>2</sub> system are related to VO<sub>2</sub> off-stoichiometry. Thus, in our case, we can assign the necessity for higher temperatures to the unbalanced cation–anion stoichiometry, owing to the partial replacement of V by Ti. Indeed, the degree of V oxidation may be reduced because a higher oxygen consumption is required for the utilization of organic residues<sup>36</sup> for the Ti precursor,  $Ti(O-i-Pr)<sub>2</sub>(TMHD)<sub>2</sub>$ , which contains four organic ligands, in contrast with only two ligands in the V-precursor,  $OV(ace)_{2}$ . According to the Ellingham diagrams, a large difference in the formation energies favors  $TiO<sub>2</sub>$  stabilization over  $VO<sub>2</sub>$  in the case of an oxygen deficiency.

Through optical measurements, we revealed a simultaneous improvement in several thermochromic parameters. These enhancements encompass the reduction of  $T_{\text{MI}}$  and  $\Delta T_{\text{MI}}$ , as well as the presence of the nanothermochromic effect due to more transparent Ti-rich layers. Well-established strategies are often effective in enhancing a specific parameter only, however, this improvement generally comes at the cost of degradation in the others.46 For instance, the incorporation of doping elements, particularly W, is undoubtedly an effective strategy for reducing  $T_{\text{MI}}$  to the desired range of 20 ÷ 25 °C, but it results in a broader transition. Similarly, nanothermochromism is a superior way for increasing luminous transmittance up to the required values of  $Tr_{\text{lum}} > 60\%$ , but this method also fails to address the issue of switching behaviour. By comparing our proposed approach with the aforementioned strategies, we can deduce that SD-assisted formation of strained  $(V, Ti)O<sub>2</sub>$ -based nanocomposites is a promising

method for the development of thermochromic coatings. While thermochromic parameters ( $T_{\text{MI}} = 53 \text{ °C}$ ,  $\Delta T_{\text{sol}} = 14\%,$  $T_{\text{Ium}}$  = 29%) achieved in this study are still quantitatively insufficient, the demonstrated potential to simultaneously enhance several crucial factors, such as MIT temperature, luminous transmittance, and switching behavior, through a single strategy provides a promising foundation for future research.

The process of spinodal decomposition encounters a notable restriction in the thickness and composition of the resulting layers due to the necessity for preserving initial  $V_{1-x}Ti_xO_2$  composition near x = 0.35. This constraint imposes limitations on the potential strain-induced enhancements. Nonetheless, our polycrystalline films have not yet reached the same level of decomposition as one achieved in bulk materials. In order to lower the  $T_{\text{MI}}$ , it is necessary to achieve a higher degree of compositional modulation during SDprocess. We believe that by increasing the compositional modulation and using a heterostrain detached from the substrate, the  $T_{\text{MI}}$  can be downshifted to the required temperatures. The sharpness and width of the NIR transmittance switching can also be advanced by increasing the compressive strain in the V-rich layers. If the nanothermochromic increase of  $T_{\text{Ium}}$  by the Ti-rich layers will be insufficient due to limitations on their maximum thickness, a further advance could be achieved by adding a third oxide component, such as ZnO, which is transparent and structurally unmixable with the  $VO<sub>2</sub>–TiO<sub>2</sub>$  system. The interrelation between the structure and composition-dependent properties of  $(V, Ti)O<sub>2</sub>$ -based nanocomposites is quite complex, and to fulfill all requirements for thermochromic coatings simultaneously, experimental work on nanocomposite metamaterials will strongly benefit from a predictive numerical simulation of their optical properties. Paper<br>
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## 4 Conclusion

Overall, using spinodal decomposition, we demonstrated the formation of strained superlattice-like nanocomposites in thin polycrystalline films of  $V_{0.65}Ti_{0.35}O_2$ . Starting during growth with the formation of atomic-scale disordered V- and Ti-rich layers, spinodal decomposition is completed by subsequent post-growth annealing, producing sharp heterointerfaces between the layers and creating a superlattice-like nanocomposite inside crystalline grains. Elastically coupled heterointerfaces between V- and Ti-rich layers generate lattice misfit strains, which compress the  $VO<sub>2</sub>$ -rich phase along the c-axis of the rutile structure and yield a strain-enhanced thermochromism with a simultaneous reduction in the temperature of the MI transition and narrowing of the hysteresis loop. In addition, the layers of the  $TiO<sub>2</sub>-rich$  phase promote luminous transmittance, according to the nanothermochromic concept. However, to meet the strict requirements for thermochromic coatings quantitatively, further improvements must be made based on thorough optimization of the entire fabrication process.

# Author contributions

A. B. conceived of the original idea and drafted the manuscript. A. B. and O. S. designed the thin film deposition system. O. S. fabricated the samples. O. S. and A. B. carried out the characterizations of the samples. V. R. performed TEM analysis. S. V. carried out XRD analysis. J. W. performed Raman spectroscopy. K. S. performed optical measurements. A. B., O. S., and V. M. contributed to the interpretation of the results. V. M. contributed to the final version of the manuscript and supervised the project. All authors discussed the results and commented on the manuscript. Nanoscale Worwington Contributions<br>
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# Conflicts of interest

There are no conflicts to declare.

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